Pin	Symbol	Function
1	GND	Logic ground
2	IN	Input, activates the power switch in case of logical high signal
3	Vbb	Positive power supply voltage, the tab is shorted to this pin
4	ST	Diagnostic feedback, low on failure
5	OUT (Load, L)	Output to the load

Maximum Ratings at T_j = 25 °C unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 3)	V_{bb}	63	V
Load dump protection $V_{LoadDump} = U_A + V_s$, U_A = 13.5 V R_I= 2 Ω, R_L= 1.1 Ω, t_d= 200 ms, IN= low or high	V_s[3)]	66.5	V
Load current (Short-circuit current, see page 4)	I_L	self-limited	A
Operating temperature range	T_j	-40 ...+150	°C
Storage temperature range	T_{stg}	-55 ...+150	
Power dissipation (DC)	P_{tot}	125	W
Inductive load switch-off energy dissipation, single pulse T_j=150 °C:	E_{AS}	1.7	J
Electrostatic discharge capability (ESD) (Human Body Model)	V_{ESD}	2.0	kV
Input voltage (DC)	V_{IN}	-0.5 ... +6	V
Current through input pin (DC)	I_{IN}	±5.0	mA
Current through status pin (DC) see internal circuit diagrams page 6...	I_{ST}	±5.0	

Thermal resistance chip - case:	R_{thJC}	≤ 1	K/W
junction - ambient (free air):	R_{thJA}	≤ 75	
SMD version, device on pcb[4)]:		typ. 33	

3) V_S is setup without DUT connected to the generator per ISO 7637-1 and DIN 40839

4) Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70µm thick) copper area for V_{bb} connection. PCB is vertical without blown air.

Electrical Characteristics

Parameter and Conditions at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Load Switching Capabilities and Characteristics					
On-state resistance (pin 3 to 5) I_L = 2 A T_j=25 °C:	R_{ON}	--	30	38	mΩ
T_j=150 °C:			55	70	
Nominal load current (pin 3 to 5) ISO Proposal: V_{ON} = 0.5 V, T_C = 85 °C	$I_{L(ISO)}$	9	11	--	A
Output current (pin 5) while GND disconnected or GND pulled up, V_{IN}= 0, see diagram page 7, T_j =-40...+150°C	$I_{L(GNDhigh)}$	--	--	1	mA
Turn-on time to 90% V_{OUT}:	t_{on}	50	160	300	µs
Turn-off time to 10% V_{OUT}:	t_{off}	10	--	80	
R_L = 12 Ω, T_j =-40...+150°C					
Slew rate on 10 to 30% V_{OUT}, R_L = 12 Ω, T_j =-40...+150°C	dV/dt_{on}	0.4	--	2.5	V/µs
Slew rate off 70 to 40% V_{OUT}, R_L = 12 Ω, T_j =-40...+150°C	$-dV/dt_{off}$	1	--	5	V/µs
Operating Parameters					
Operating voltage [5] T_j =-40...+150°C:	$V_{bb(on)}$	4.5	--	42	V
Undervoltage shutdown T_j =-40...+150°C:	$V_{bb(under)}$	2.4	--	4.5	V
Undervoltage restart T_j =-40...+150°C:	$V_{bb(u\ rst)}$	--	--	4.5	V
Undervoltage restart of charge pump see diagram page 12 T_j =-40...+150°C:	$V_{bb(ucp)}$	--	6.5	7.5	V
Undervoltage hysteresis $\Delta V_{bb(under)} = V_{bb(u\ rst)} - V_{bb(under)}$	$\Delta V_{bb(under)}$	--	0.2	--	V
Overvoltage shutdown T_j =-40...+150°C:	$V_{bb(over)}$	42	--	52	V
Overvoltage restart T_j =-40...+150°C:	$V_{bb(o\ rst)}$	42	--	--	V
Overvoltage hysteresis T_j =-40...+150°C:	$\Delta V_{bb(over)}$	--	0.2	--	V
Overvoltage protection[6] T_j =-40°C:	$V_{bb(AZ)}$	60	--	--	V
I_{bb}=40 mA T_j =25...+150°C:		63	67		
Standby current (pin 3) T_j=-40...+25°C:	$I_{bb(off)}$	--	12	25	µA
V_{IN}=0 T_j=150°C:		--	18	60	
Leakage output current (included in $I_{bb(off)}$) V_{IN}=0	$I_{L(off)}$	--	6	--	µA
Operating current (Pin 1)[7], V_{IN}=5 V	I_{GND}	--	1.1	--	mA

5) At supply voltage increase up to V_{bb}= 6.5 V typ without charge pump, $V_{OUT} \approx V_{bb}$ - 2 V

6) see also $V_{ON(CL)}$ in table of protection functions and circuit diagram page 7. Meassured without load.

7) Add I_{ST}, if I_{ST} > 0, add I_{IN}, if V_{IN}>5.5 V

Parameter and Conditions at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Protection Functions[8]					
Initial peak short circuit current limit (pin 3 to 5)[9], (max 400 µs if $V_{ON} > V_{ON(SC)}$)	$I_{L(SCp)}$				
T_j =-40°C:		--	--	74	A
T_j =25°C:		--	44	--	
T_j =+150°C:		24	--	--	
Repetitive short circuit current limit $T_j = T_{jt}$ (see timing diagrams, page 10)	$I_{L(SCr)}$	22	35	--	A
Short circuit shutdown delay after input pos. slope $V_{ON} > V_{ON(SC)}$, T_j =-40..+150°C: min value valid only, if input "low" time exceeds 30 µs	$t_{d(SC)}$	80	--	400	µs
Output clamp (inductive load switch off) at $V_{OUT} = V_{bb} - V_{ON(CL)}$, I_L= 30 mA	$V_{ON(CL)}$	--	58	--	V
Short circuit shutdown detection voltage (pin 3 to 5)	$V_{ON(SC)}$	--	8.3	--	V
Thermal overload trip temperature	T_{jt}	150	--	--	°C
Thermal hysteresis	ΔT_{jt}	--	10	--	K
Inductive load switch-off energy dissipation[10], $T_{j\,Start}$ = 150 °C, single pulse	E_{AS}	--	--	1.7	J
V_{bb} = 12 V:	E_{Load12}			1.3	
V_{bb} = 24 V:	E_{Load24}			1.0	
Reverse battery (pin 3 to 1) [11]	$-V_{bb}$	--	--	32	V
Integrated resistor in V_{bb} line	R_{bb}	--	120	--	Ω
Diagnostic Characteristics					
Open load detection current (on-condition) T_j=-40 °C:	$I_{L\,(OL)}$	2	--	900	mA
T_j=25..150°C:		2	--	750	

8) Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

9) Short circuit current limit for max. duration of 400 µs, prior to shutdown (see $t_{d(SC)}$ page 4)

10) While demagnetizing load inductance, dissipated energy in PROFET is $E_{AS} = \int V_{ON(CL)} * i_L(t)\,dt$, approx. $E_{AS} = {}^1/_2 * L * I_L^2 * \left(\frac{V_{ON(CL)}}{V_{ON(CL)} - V_{bb}}\right)$, see diagram page 8.

11) Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load. Reverse current I_{GND} of ≈ 0.3 A at V_{bb}= -32 V through the logic heats up the device. Time allowed under these condition is dependent on the size of the heatsink. Reverse I_{GND} can be reduced by an additional external GND-resistor (150 Ω). Input and Status currents have to be limited (see max. ratings page 2 and circuit page 7).

Parameter and Conditions at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Input and Status Feedback[12)]					
Input turn-on threshold voltage ⟋ T_j =-40..+150°C:	$V_{IN(T+)}$	1.5	--	2.4	V
Input turn-off threshold voltage ⟍ T_j =-40..+150°C:	$V_{IN(T-)}$	1.0	--	--	V
Input threshold hysteresis	$\Delta V_{IN(T)}$	--	0.5	--	V
Off state input current (pin 2) V_{IN} = 0.4 V:	$I_{IN(off)}$	1	--	30	µA
On state input current (pin 2) V_{IN} = 3.5 V:	$I_{IN(on)}$	10	25	50	µA
Status invalid after positive input slope (short circuit) T_j=-40 ... +150°C:	$t_{d(ST\ SC)}$	80	200	400	µs
Status invalid after positive input slope (open load) T_j=-40 ... +150°C:	$t_{d(ST)}$	350	--	1600	µs
Status output (open drain)					
Zener limit voltage T_j =-40...+150°C, I_{ST} = +1.6 mA:	$V_{ST(high)}$	5.4	6.1	--	V
ST low voltage T_j =-40...+150°C, I_{ST} = +1.6 mA:	$V_{ST(low)}$	--	--	0.4	

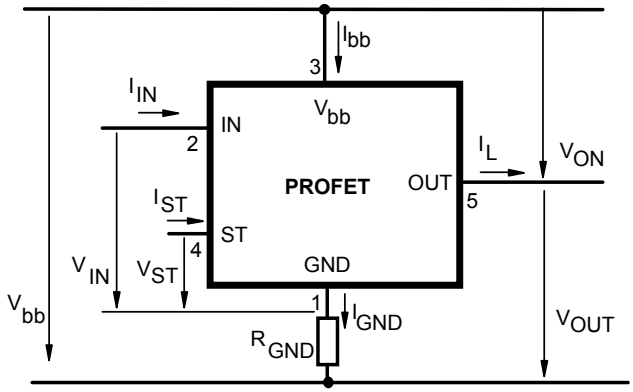
12) If a ground resistor R_{GND} is used, add the voltage drop across this resistor.

Truth Table

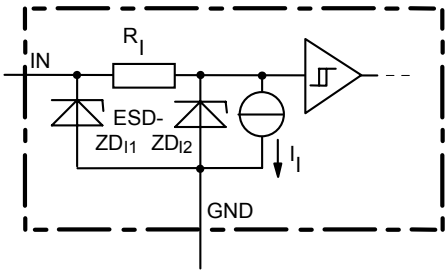
	Input-Level	Output level	Status 432E2
Normal operation	L H	L H	H H
Open load	L H	13) H	H L
Short circuit to GND	L H	L L	H L
Short circuit to V_{bb}	L H	H H	H H (L[14])
Overtem-perature	L H	L L	L L
Under-voltage	L H	L L	H H
Overvoltage	L H	L L	H H

L = "Low" Level
H = "High" Level

Terms



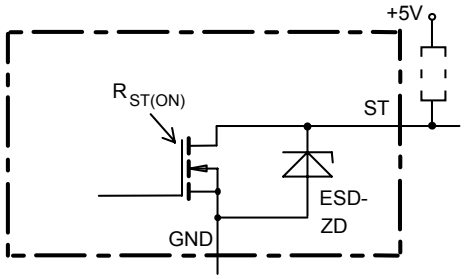
Input circuit (ESD protection)



ZD_{I1} 6.1 V typ., ESD zener diodes are not designed for continuous current

13) Power Transistor off, high impedance
14) Low resistance short V_{bb} to output may be detected by no-load-detection

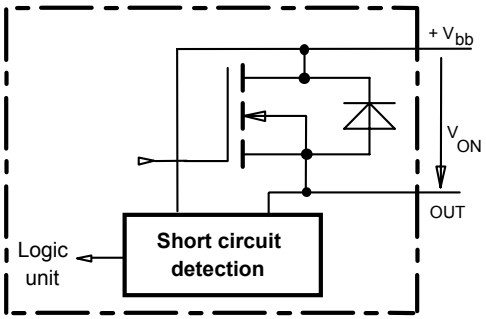
Status output



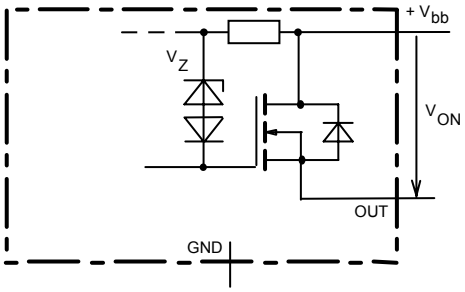
ESD-Zener diode: 6.1 V typ., max 5 mA;
$R_{ST(ON)}$ < 250 Ω at 1.6 mA, ESD zener diodes are not designed for continuous current

Short Circuit detection

Fault Condition: V_{ON} > 8.3 V typ.; IN high

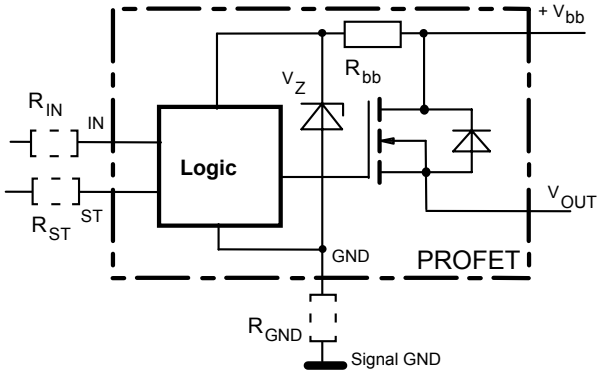


Inductive and overvoltage output clamp



V_{ON} clamped to 58 V typ.

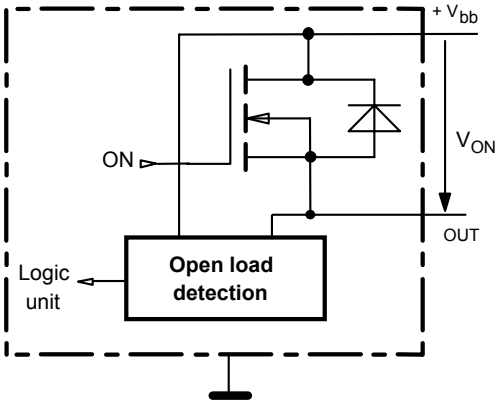
Overvolt. and reverse batt. protection



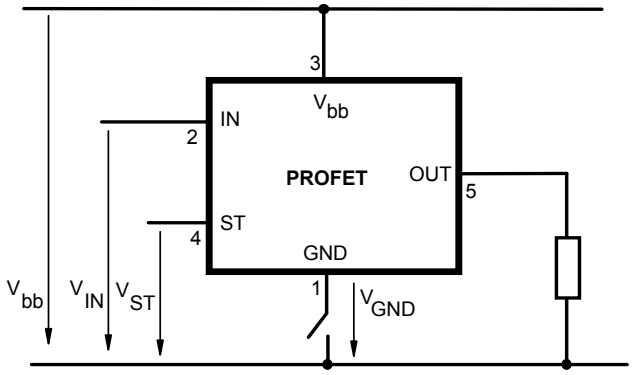
R_{bb} = 120 Ω typ., V_Z +R_{bb}*40 mA = 67 V typ., add R_{GND}, R_{IN}, R_{ST} for extended protection

Open-load detection

ON-state diagnostic condition: V_{ON} < R_{ON} * $I_{L(OL)}$; IN high

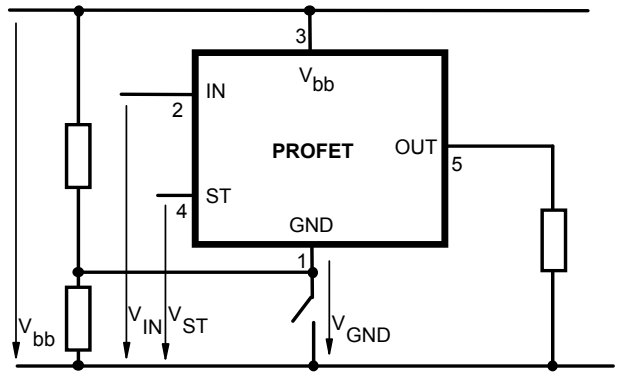


GND disconnect

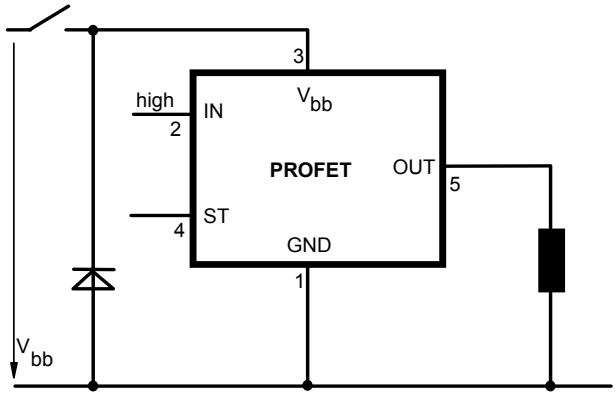


Any kind of load. In case of Input=high is $V_{OUT} \approx V_{IN} - V_{IN(T+)}$.
Due to V_{GND} >0, no V_{ST} = low signal available.

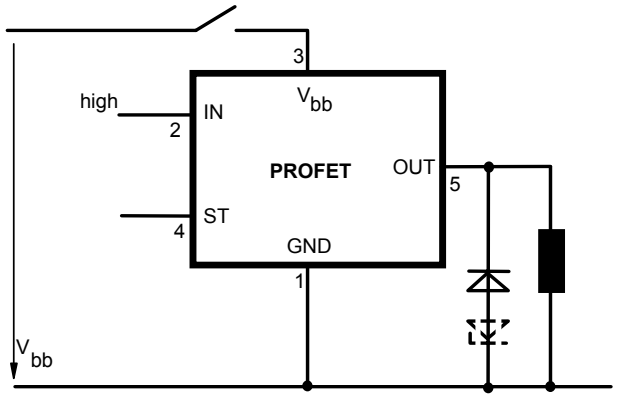
GND disconnect with GND pull up



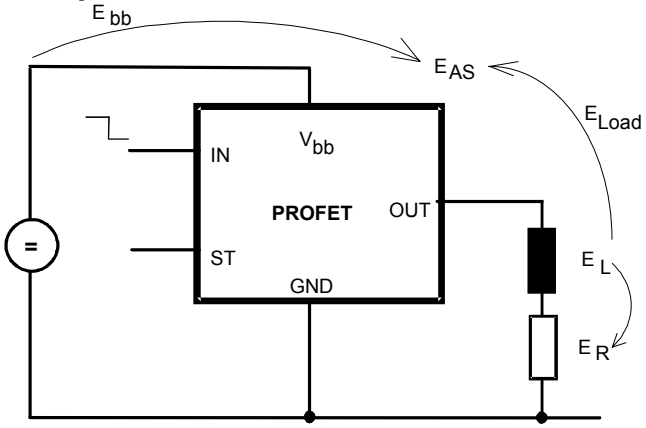
Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off
Due to $V_{GND} > 0$, no V_{ST} = low signal available.



V_{bb} disconnect with charged inductive load



Inductive Load switch-off energy dissipation



Energy dissipated in PROFET $E_{AS} = E_{bb} + E_L - E_R$.
$E_{Load} < E_L$, $E_L = {}^1/_2 * L * I_L^2$

Options Overview

all versions: High-side switch, Input protection, ESD protection, load dump and reverse battery protection , protection against loss of ground

Type BTS	432E2
Logic version	E
Overtemperature protection	
T_j >150 °C, latch function[15)16)]	
T_j >150 °C, with auto-restart on cooling	X
Short-circuit to GND protection	
switches off when V_{ON}>8.3 V typ.[15)] (when first turned on after approx. 200 µs)	X
Open load detection	
in OFF-state with sensing current 30 µA typ.	
in ON-state with sensing voltage drop across power transistor	X
Undervoltage shutdown with auto restart	X
Overvoltage shutdown with auto restart	X
Status feedback for	
overtemperature	X
short circuit to GND	X
short to V_{bb}	-[17)]
open load	X
undervoltage	-
overvoltage	-
Status output type	
CMOS	
Open drain	X
Output negative voltage transient limit (fast inductive load switch off)	
to V_{bb} - $V_{ON(CL)}$	X
Load current limit	
high level (can handle loads with high inrush currents)	X
medium level	
low level (better protection of application)	

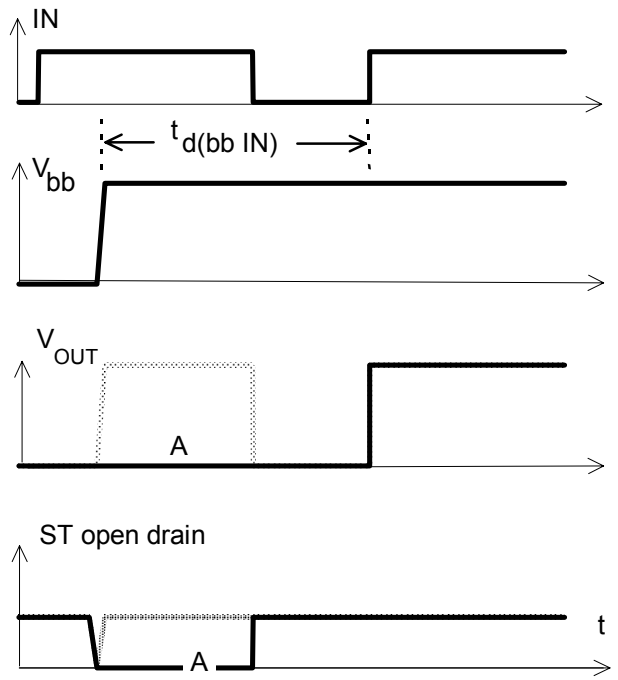
15) Latch except when V_{bb} - V_{OUT} < $V_{ON(SC)}$ after shutdown. In most cases V_{OUT} = 0 V after shutdown (V_{OUT} ≠ 0 V only if forced externally). So the device remains latched unless V_{bb} < $V_{ON(SC)}$ (see page 4). No latch between turn on and $t_{d(SC)}$.

16) With latch function. Reseted by a) Input low, b) Undervoltage, c) Overvoltage

17) Low resistance short V_{bb} to output may be detected by no-load-detection

Timing diagrams

Figure 1a: V_{bb} turn on:



in case of too early V_{IN}=high the device may not turn on (curve A)
$t_{d(bb\ IN)}$ approx. 150 µs

Figure 2a: Switching a lamp,

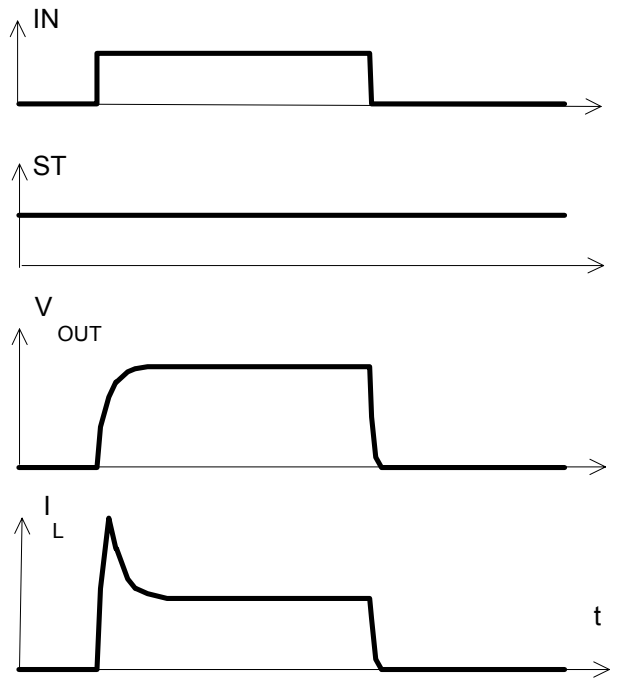
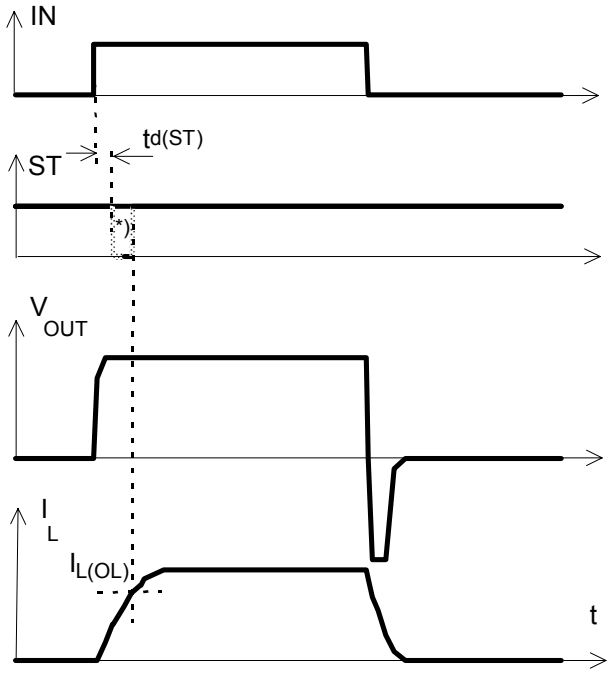
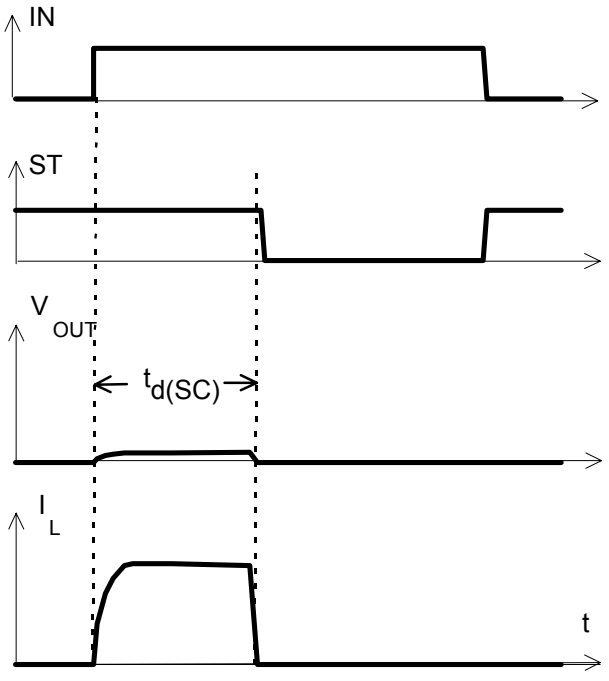


Figure 2b: Switching an inductive load



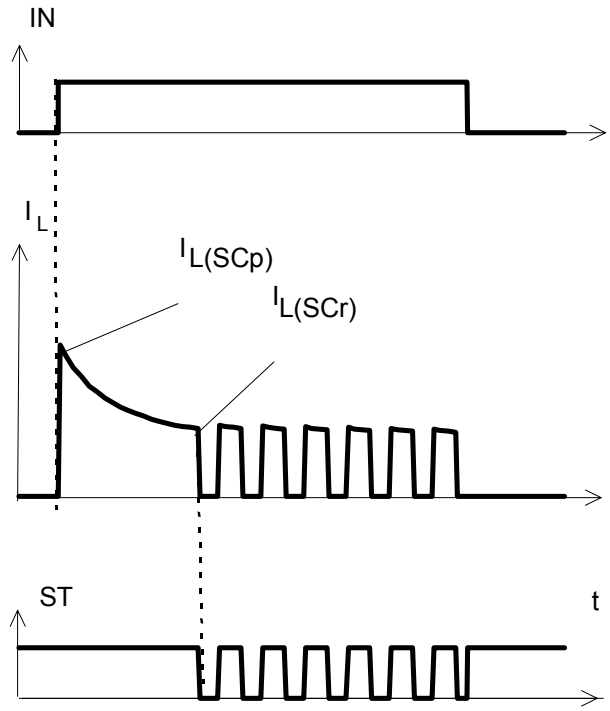
*) if the time constant of load is too large, open-load-status may occur

Figure 3a: Turn on into short circuit,



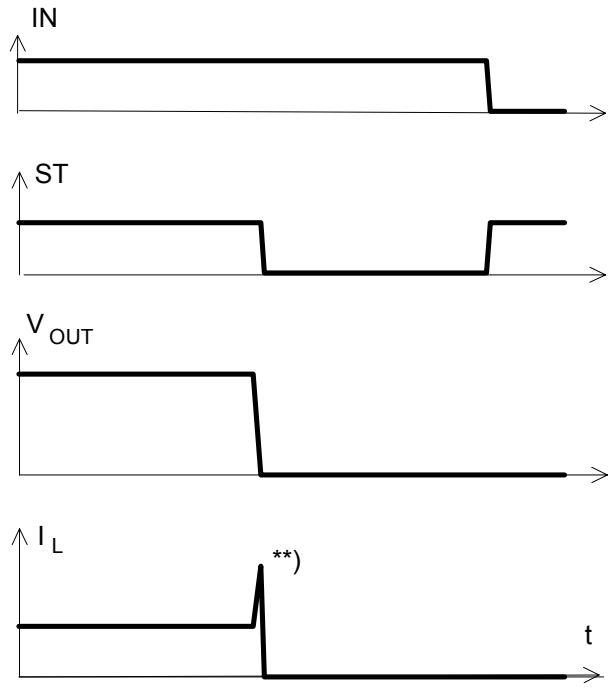
$t_{d(SC)}$ approx. 200µs if V_{bb} - V_{OUT} > 8.3 V typ.

Figure 3b: Turn on into overload,



Heating up may require several milliseconds , V_{bb} - V_{OUT} < 8.3 V typ.

Figure 3c: Short circuit while on:



**) current peak approx. 20 µs

Figure 4a: Overtemperature:
Reset if $T_j < T_{jt}$

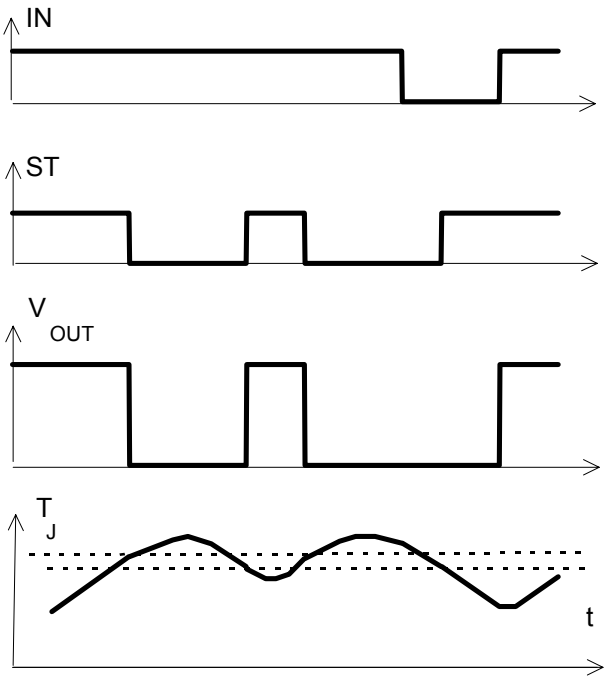


Figure 5a: Open load: detection in ON-state, turn on/off to open load

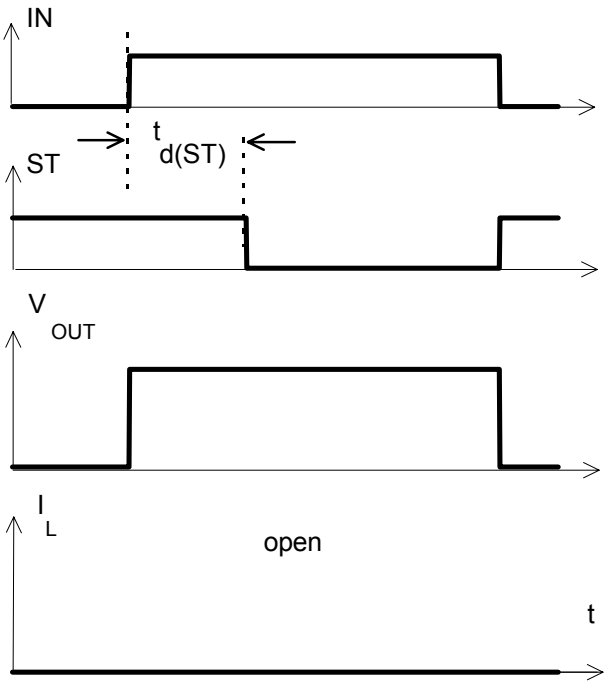
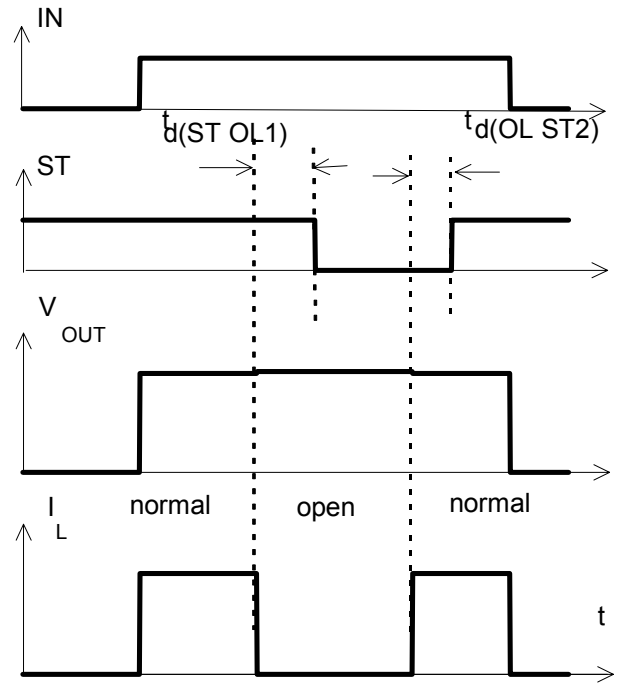


Figure 5b: Open load: detection in ON-state, open load occurs in on-state



$t_{d(ST\ OL1)}$ = tbd µs typ., $t_{d(ST\ OL2)}$ = tbd µs typ

Figure 6a: Undervoltage:

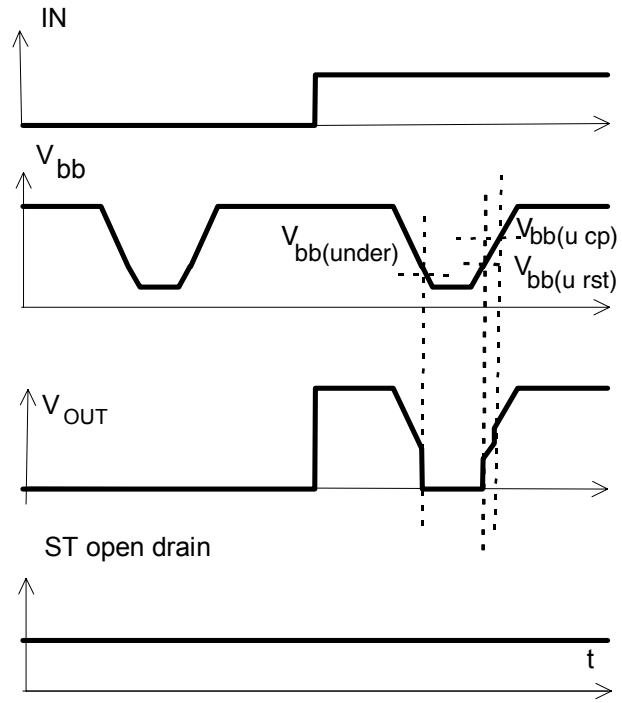
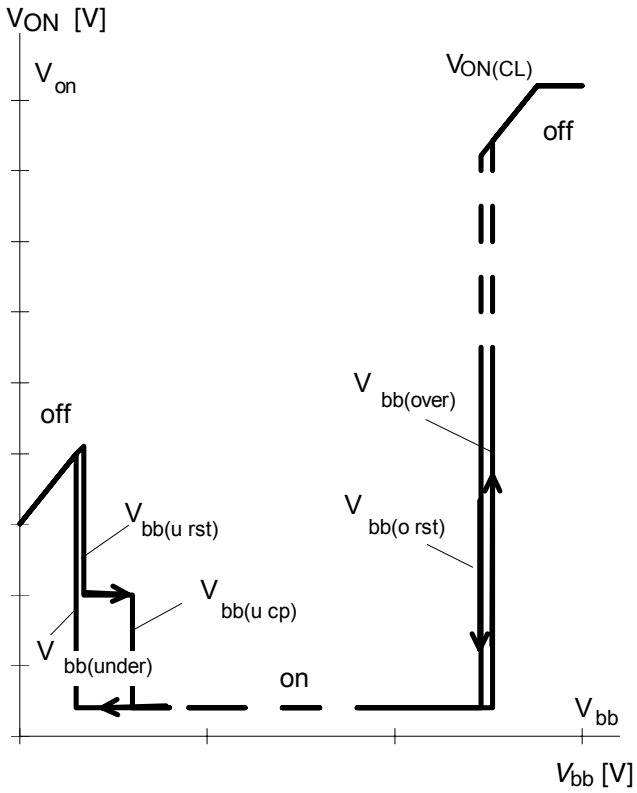
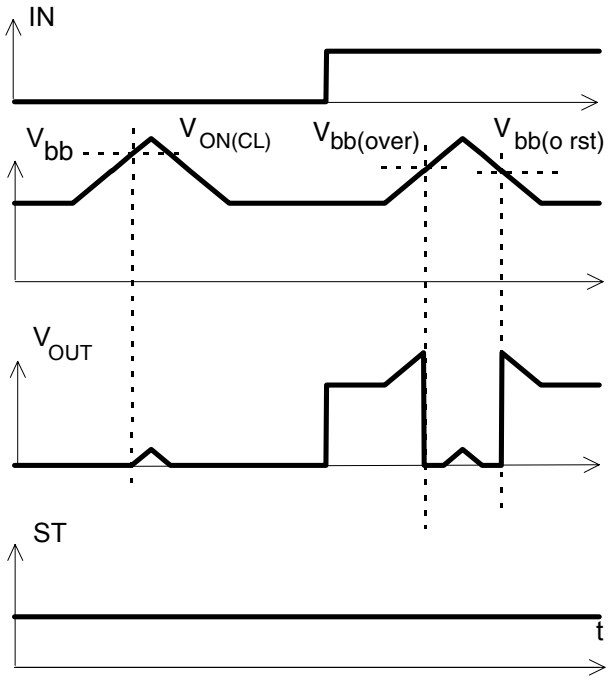


Figure 6b: Undervoltage restart of charge pump



charge pump starts at $V_{bb(ucp)}$ =6.5 V typ.

Figure 7a: Overvoltage:

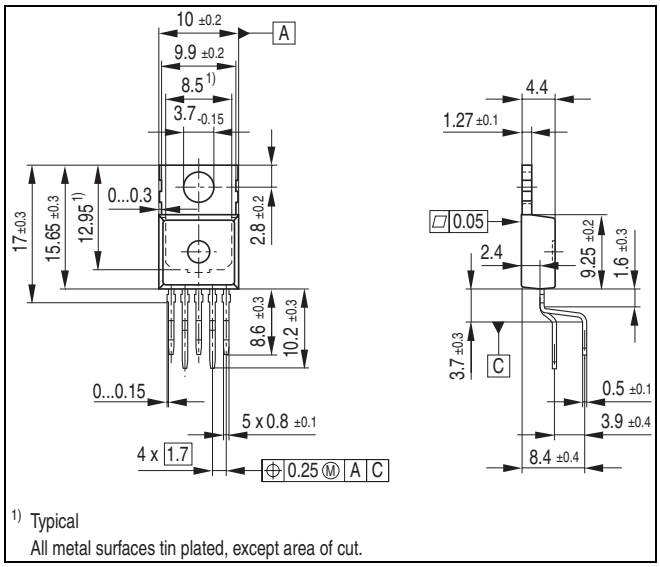


Package and Ordering Code

All dimensions in mm

PG-TO220-5-11

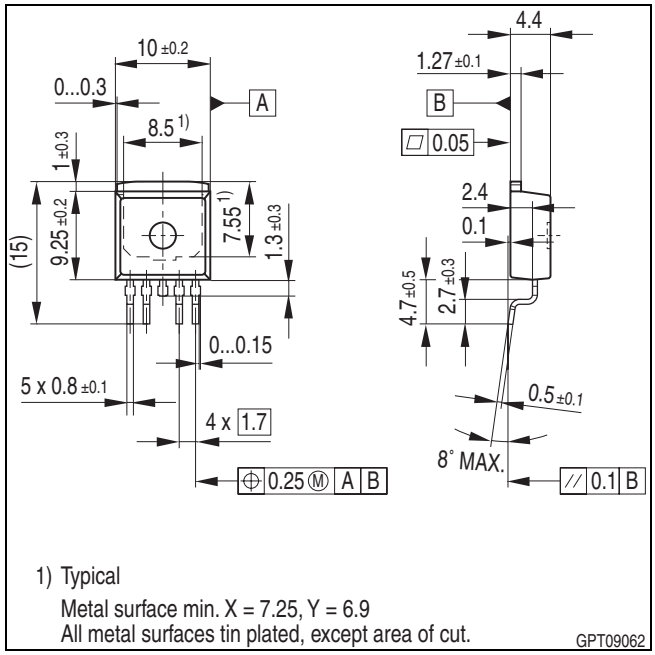
BTS 432 E2	



1) Typical
All metal surfaces tin plated, except area of cut.

SMD PG-TO263-5-2

BTS432E2 E3062A	



1) Typical
Metal surface min. X = 7.25, Y = 6.9
All metal surfaces tin plated, except area of cut.
GPT09062

Green Product

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Revision History

Version	Date	Changes
Rev. 1.1	2010-01-26	Page 13: Package drawing for PG-TO220-5-11 corrected.
Rev. 1.0	2009-11-12	RoHS-compliant version of BTS432E2 Removal of straight lead package variant E3043 Page 1, page 13: RoHS compliance statement and Green product feature added Page 1, page 13: Change to RoHS compliant packages; PG-TO220-5-11 for standard (staggered) variant; PG-TO263-5-2 for E3062A variant. Page 2: Thermal resistance junction to ambient for SMD version set to typically 33K/W. Page 2: Pin marking removed. Page 6, 9: Discontinued variants removed from truth table & options overview. Legal disclaimer updated

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Information
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